

X4-Class **Power MOSFET**

IXTP60N20X4

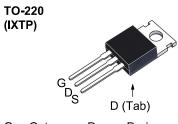
N-Channel Enhancement Mode Avalanche Rated



Symbol	Test Conditions	Maximum Ratings		
V _{DSS} V _{DGR}	$T_J = 25$ °C to 175°C $T_J = 25$ °C to 175°C, $R_{GS} = 1M\Omega$	200 200	V	
V _{GS} V _{GSM}	Continuous Transient	±20 ±30	V	
I _{D25}	$T_{_{\rm C}} = 25^{\circ}\text{C}$ $T_{_{\rm C}} = 25^{\circ}\text{C}$, Pulse Width Limited by $T_{_{\rm JM}}$	60 106	A A	
I _A E _{AS}	$T_{c} = 25$ °C $T_{c} = 25$ °C	30 350	A mJ	
dv/dt	$I_{S} \le I_{DM}, V_{DD} \le V_{DSS}, T_{J} \le 150^{\circ}C$	50	V/ns	
$\overline{\mathbf{P}_{D}}$	T _c = 25°C	250	W	
T _J T _{JM} T _{stg}		-55 +175 175 -55 +175	°C °C °C	
T _L	Maximum Lead Temperature for Soldering 1.6 mm (0.062 in.) from Case for 10s	300	°C	
M _d	Mounting Torque	1.13 / 10	Nm/lb.in	
Weight		3	g	

SymbolTest ConditionsCharacteristics $(T_J = 25^{\circ}C, Unless Otherwise Specified)$ Min.		acteristic Values Typ. Max.		
BV _{DSS}	$V_{GS} = 0V, I_{D} = 250 \mu A$	200		V
$V_{\rm GS(th)}$	$V_{DS} = V_{GS}, I_{D} = 250 \mu A$	2.5		4.5 V
GSS	$V_{GS} = \pm 20V, V_{DS} = 0V$			±100 nA
Dss	$V_{DS} = V_{DSS}, V_{GS} = 0V$ $T_{J} = 150 ^{\circ}C$			5 μA 300 μA
R _{DS(on)}	$V_{GS} = 10V, I_{D} = 0.5 \cdot I_{D25}, Note 1$		17.6	21.0 mΩ

 $\boldsymbol{V}_{\text{DSS}}$ 200V = 60A $21.0 m\Omega$ $\boldsymbol{R}_{\text{DS(on)}}$



G = Gate D = Drain S = Source Tab = Drain

Features

- International Standard Package
- Low $R_{DS(ON)}$ and Q_G
- Avalanche Rated
- Low Package Inductance

Advantages

- High Power Density
- Easy to Mount
- Space Savings

Applications

- Switch-Mode and Resonant-Mode Power Supplies
- DC-DC Converters
- PFC Circuits
- AC and DC Motor Drives
- Robotics and Servo Controls

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		Charact Min.	cteristic Values ∣ Typ. ∣Max		
g _{fs}	V _{DS} = 10V, I _D = 0.5 • I _{D25} , Note 1	34	56	S	
R_{Gi}	Gate Input Resistance		7.45	Ω	
C _{iss}			2450	pF	
C _{oss}	$V_{GS} = 0V, V_{DS} = 25V, f = 1MHz$		406	pF	
C _{rss}			0.95	pF	
	Effective Output Capacitance				
C _{o(er)}	Energy related $\int V_{GS} = 0V$		240	pF	
$\mathbf{C}_{\mathrm{o(tr)}}$	Time related $\int V_{DS}^{gs} = 0.8 \cdot V_{DSS}$		880	pF	
t _{d(on)}	Decision Contabina Times		13	ns	
t,	Resistive Switching Times $V{GS} = 10V, V_{DS} = 0.5 \cdot V_{DSS}, I_{D} = 0.5 \cdot I_{D25}$		22	ns	
t _{d(off)}			52	ns	
t _f	$R_{_{\rm G}} = 5\Omega$ (External)		10	ns	
$Q_{g(on)}$			33	nC	
Q_{gs}	$V_{GS} = 10V, V_{DS} = 0.5 \cdot V_{DSS}, I_{D} = 0.5 \cdot I_{D25}$		9	nC	
\mathbf{Q}_{gd}			11	nC	
R _{thJC}				0.60 °C/W	
R _{thCS}			0.50	°C/W	

Source-Drain Diode

Symbol (T = 25°C	Test Conditions Unless Otherwise Specified)	Characteristic Values Min. Typ. Max			
I _s	V _{GS} = 0V		. 7 (2)	60	A
SM	Repetitive, Pulse Width Limited by T_{JM}			240	Α
V _{SD}	$I_F = I_S, V_{GS} = 0V, \text{ Note } 1$			1.4	V
$\left. egin{array}{l} oldsymbol{t}_{rr} & \ oldsymbol{Q}_{RM} & \ oldsymbol{I}_{RM} & \end{array} ight. ight.$	$I_F = 30A$, -di/dt = 200A/ μ s $V_R = 100V$		107 920 17		ns nC A

Note 1: Pulse test, $t \leq 300 \mu s,$ duty cycle, d ≤ 2 %

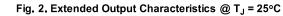
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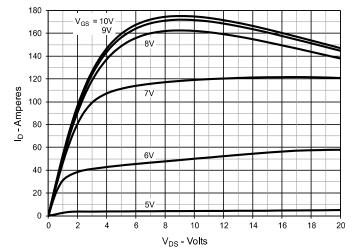
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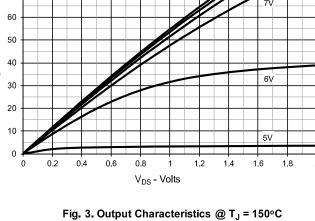
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V_{GS} = 10V 9V 8V

Fig. 1. Output Characteristics @ T_J = 25°C







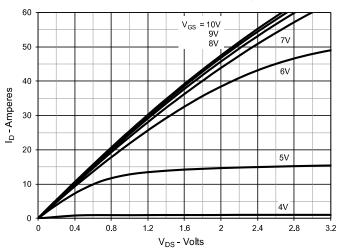
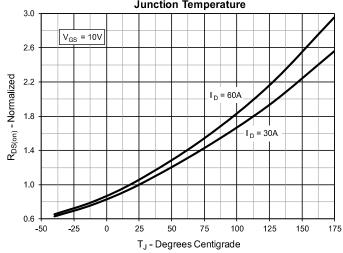
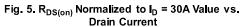


Fig. 4. $R_{DS(on)}$ Normalized to I_D = 30A Value vs. Junction Temperature





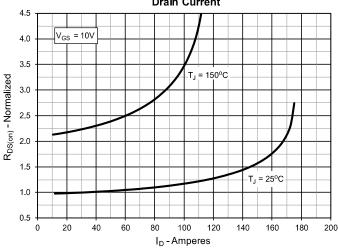
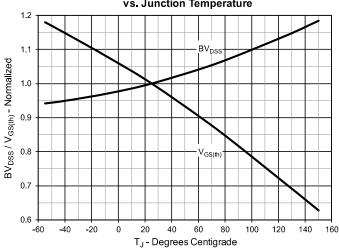


Fig. 6. Normalized Breakdown & Threshold Voltages vs. Junction Temperature



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Fig. 7. Maximum Drain Current vs. Case Temperature

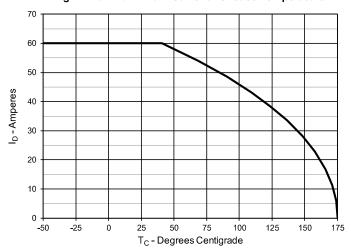


Fig. 8. Input Admittance

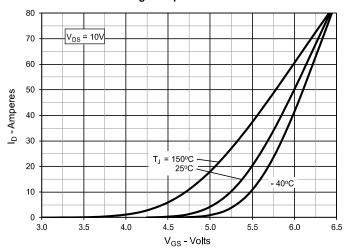


Fig. 9. Transconductance

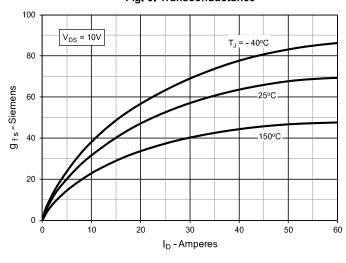


Fig. 10. Forward Voltage Drop of Intrinsic Diode

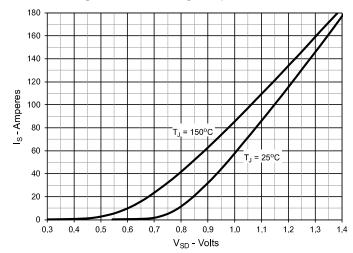


Fig. 11. Gate Charge

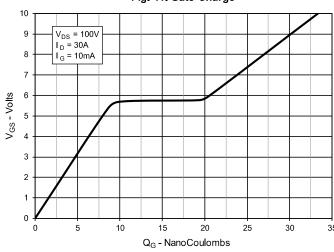
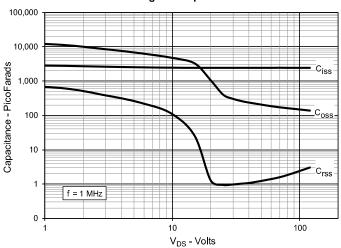
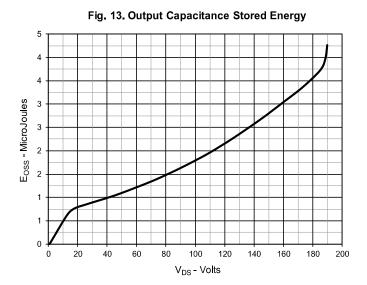


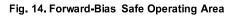
Fig. 12. Capacitance



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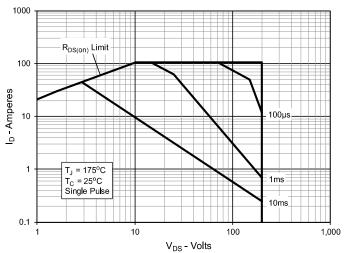
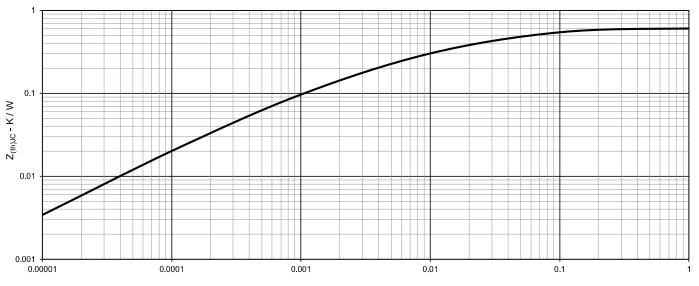


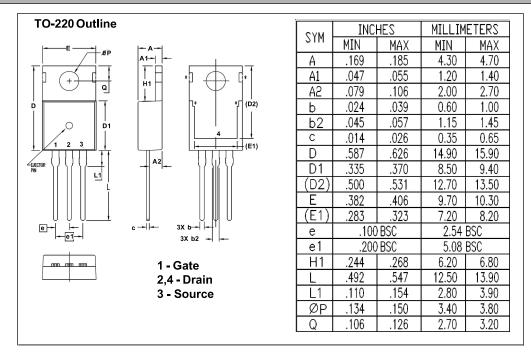
Fig. 15. Maximum Transient Thermal Impedance



Pulse Width - Second

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